

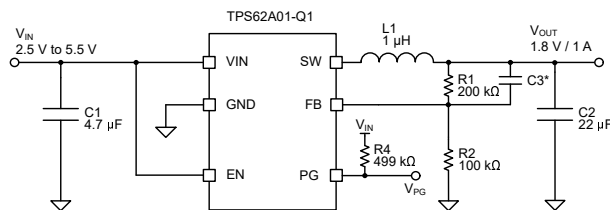
TPS62A01x-Q1 2.5V~5.5V、1A 車載用降圧コンバータ、SOT563 パッケージ

1 特長

- 入力電圧範囲: 2.5V~5.5V
- 車載アプリケーション向けに AEC-Q100 認定済み
 - デバイス温度グレード 1: -40°C~+125°C、T_A
- 可変出力電圧範囲: 0.6V~V_{IN}
- 100mΩ および 67mΩ 低 R_{DS(on)} スイッチ
- 静止電流: 25μA 未満
- タイミング精度: 1.5% (-40°C~150°C)
- 100% モード動作
- スイッチング周波数: 2.4MHz
- パワー・セーブ・モードまたは PWM オプションが利用可能
- パワー・グッド出力ピン
- 短絡保護 (HICCUP)
- ソフト・スタートアップを内蔵
- アクティブ出力放電
- サーマル・シャットダウン保護機能
- 1.60mm × 1.60mm の SOT563 パッケージで供給

2 アプリケーション

- フロント・カメラ
- サラウンド・ビュー・システムの ECU
- 車載用クラスター・ディスプレイ



代表的なアプリケーション

3 概要

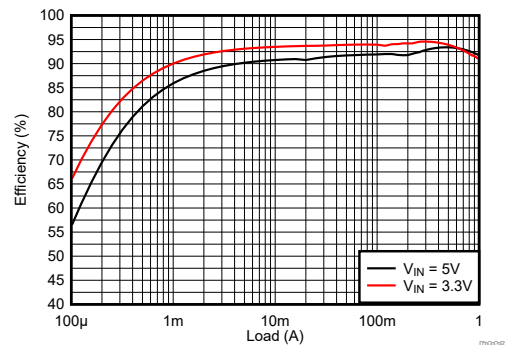
TPS62A01x-Q1 デバイス ファミリーは同期整流降圧型 DC/DC コンバータで、高効率と小型の設計向けに最適化されています。このデバイスは最大 1A の出力電流を供給できるスイッチを内蔵しています。中~高負荷時には、スイッチング周波数 2.4MHz のパルス幅変調 (PWM) で動作します。軽負荷時には、デバイスは自動的にパワー・セーブ・モード (PSM) へ移行し、負荷電流範囲の全体にわたって高い効率を維持します。シャットダウン時には、消費電流も最小限に抑えられます。このデバイス・ファミリーの TPS62A01A-Q1 のバリエーションでは、負荷電流範囲全体にわたって強制 PWM で動作します。

TPS62A01x-Q1 デバイスは、外付けの分圧抵抗によって出力電圧を変更できます。内部のソフト・スタート回路により、スタートアップ時の突入電流が制限されます。過電流保護、サーマル・シャットダウン保護、パワー・グッドなど、その他の機能も備えています。本デバイスは SOT563 パッケージで供給されます。

製品情報

部品番号 (2)	動作モード	パッケージ (1)	パッケージ・サイズ (3)
TPS62A01-Q1	PSM, PWM	DRL (SOT-563, 6)	1.60mm × 1.60mm
TPS62A01A-Q1	FPWM		

- 詳細については、[セクション 11](#) を参照してください。
- [製品比較表](#) を参照してください。
- パッケージ・サイズ (長さ×幅) は公称値であり、該当する場合はピンも含まれます。



1.8V_{IN} での出力電流と効率の関係



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4 Device Comparison Table

Device Number	Output Current	Operation Mode
TPS62A01-Q1	1 A	PSM, PWM
TPS62A01A-Q1	1 A	FPWM

5 Pin Configuration and Functions

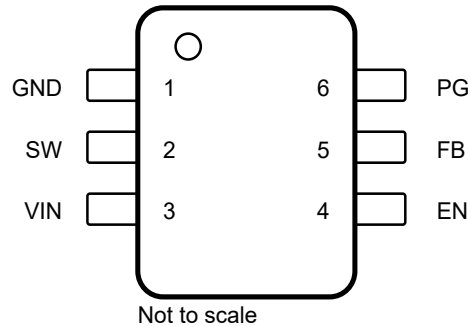


図 5-1. 6-Pin DRL SOT-563 Package (Top View)

表 5-1. Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
EN	4	I	Device enable logic input. Logic high enables the device. Logic low disables the device and turns the device into shutdown. Do not leave the pin floating.
FB	5	I	Feedback pin for the internal control loop. Connect this pin to an external feedback divider.
GND	1	G	Ground pin
PG	6	O	Power-good open-drain output pin. The pullup resistor cannot be connected to any voltage higher than 5.5 V. If unused, leave the pin open or connect to GND.
SW	2	O	Switch pin connected to the internal FET switches and inductor terminal. Connect the inductor of the output filter to this pin.
VIN	3	I	Power supply voltage pin

(1) I = Input, O = Output, G = Ground

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

		MIN	MAX	UNIT
Pin voltage ⁽²⁾	VIN, EN, PG	-0.3	6	V
	SW, DC	-0.3	V _{IN} + 0.3	V
	SW, transient < 10 ns	-3.0	10	V
	FB	-0.3	3	V
T _J	Operating junction temperature	-40	150	°C
T _{stg}	Storage temperature	-55	150	°C

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) All voltage values are with respect to the network ground terminal.

6.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 ⁽¹⁾	±2000	V
		Charged device model (CDM), per AEC Q100-011	±750	

- (1) AEC Q100-002 indicates that HBM stressing must be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

Over operating junction temperature range (unless otherwise noted)

			MIN	NOM	MAX	UNIT
V _{IN}	Input supply voltage range		2.5		5.5	V
V _{OUT}	Output voltage range		0.6		V _{IN}	V
I _{OUT}	Output current range	TPS62A01			1	A
L	Effective inductance			1.0		μH
I _{PG}	Power-Good input current capability		0		1	mA
T _J	Operating junction temperature		-40		150	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS62A01(A)-Q1		UNIT
		JEDEC	EVM	
		6 PINS		
R _{θJA}	Junction-to-ambient thermal resistance	154.2	122.7	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	85.3	n/a ⁽²⁾	°C/W
R _{θJB}	Junction-to-board thermal resistance	42.9	n/a ⁽²⁾	°C/W
ψ _{JT}	Junction-to-top characterization parameter	2.6	2.7	°C/W
ψ _{JB}	Junction-to-board characterization parameter	42.4	42.1	°C/W

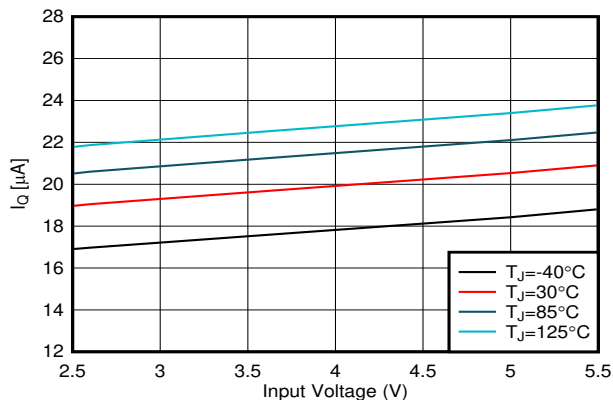
- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) report.
- (2) Not applicable to an EVM.

6.5 Electrical Characteristics

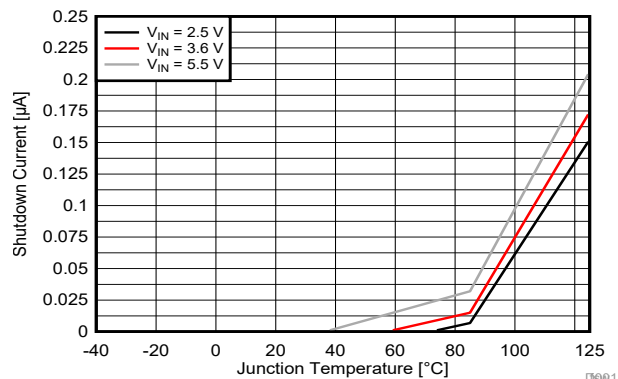
$T_J = -40^{\circ}\text{C}$ to $+150^{\circ}\text{C}$, $V_{IN} = 2.5\text{ V}$ to 5.5 V . Typical values are at $T_J = 25^{\circ}\text{C}$ and $V_{IN} = 5\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY						
$I_{Q(VIN)}$	VIN quiescent current	Non-switching, $V_{EN} = \text{High}$, $V_{FB} = 610\text{ mV}$		23		μA
$I_{SD(VIN)}$	VIN shutdown supply current	$V_{EN} = \text{Low}$		0.01	4	μA
UVLO						
$V_{UVLO(R)}$	VIN UVLO rising threshold	V_{IN} rising	2.3	2.4	2.5	V
$V_{UVLO(F)}$	VIN UVLO falling threshold	V_{IN} falling	2.2	2.3	2.4	V
ENABLE						
$V_{EN(R)}$	High-level input voltage (EN)	EN rising, enable switching	1.2			V
$V_{EN(F)}$	Low-level input voltage (EN)	EN falling, disable switching			0.4	V
$V_{EN(LKG)}$	EN Input leakage current	$V_{EN} = 5\text{ V}$			250	nA
REFERENCE VOLTAGE						
V_{FB}	FB voltage	PWM mode	591	600	609	mV
$I_{FB(LKG)}$	FB input leakage current	$V_{FB} = 0.6\text{ V}$			100	nA
SWITCHING FREQUENCY						
$f_{SW(FCCM)}$	Switching frequency, FPWM operation	$V_{IN} = 5\text{ V}$; $V_{OUT} = 1.8\text{ V}$		2400		kHz
STARTUP						
	Internal fixed soft-start time	From EN = High to $V_{FB} = 0.56\text{ V}$			1	ms
POWER STAGE						
$R_{DS(ON)(HS)}$	High-side MOSFET on-resistance	$V_{IN} = 5\text{ V}$		100		m Ω
$R_{DS(ON)(LS)}$	Low-side MOSFET on-resistance	$V_{IN} = 5\text{ V}$		67		m Ω
OVERCURRENT PROTECTION						
$I_{HS(OC)}$	High-side peak current limit		1.5	1.8		A
$I_{LS(OC)}$	Low-side valley current limit			1.8		A
POWER GOOD						
V_{PGTH}	Power Good threshold	PG low, FB falling		93.5		%
V_{PGTH}	Power Good threshold	PG high, FB rising		96		%
	PG delay falling			35		μs
	PG delay rising			10		μs
$I_{PG(LKG)}$	PG pin Leakage current when open drain output is high	$V_{PG} = 5\text{ V}$			100	nA
	PG pin output low-level voltage	$I_{PG} = 1\text{ mA}$			400	mV
OUTPUT DISCHARGE						
	Output discharge current on SW pin	$V_{IN} = 3\text{ V}$, $V_{OUT} = 2.0\text{ V}$		76		mA
THERMAL SHUTDOWN						
$T_{J(SD)}$	Thermal shutdown threshold	Temperature rising		170		$^{\circ}\text{C}$
$T_{J(HYS)}$	Thermal shutdown hysteresis			20		$^{\circ}\text{C}$

6.6 Typical Characteristics



6-1. Quiescent Current vs Input Voltage (TPS62A01-Q1)



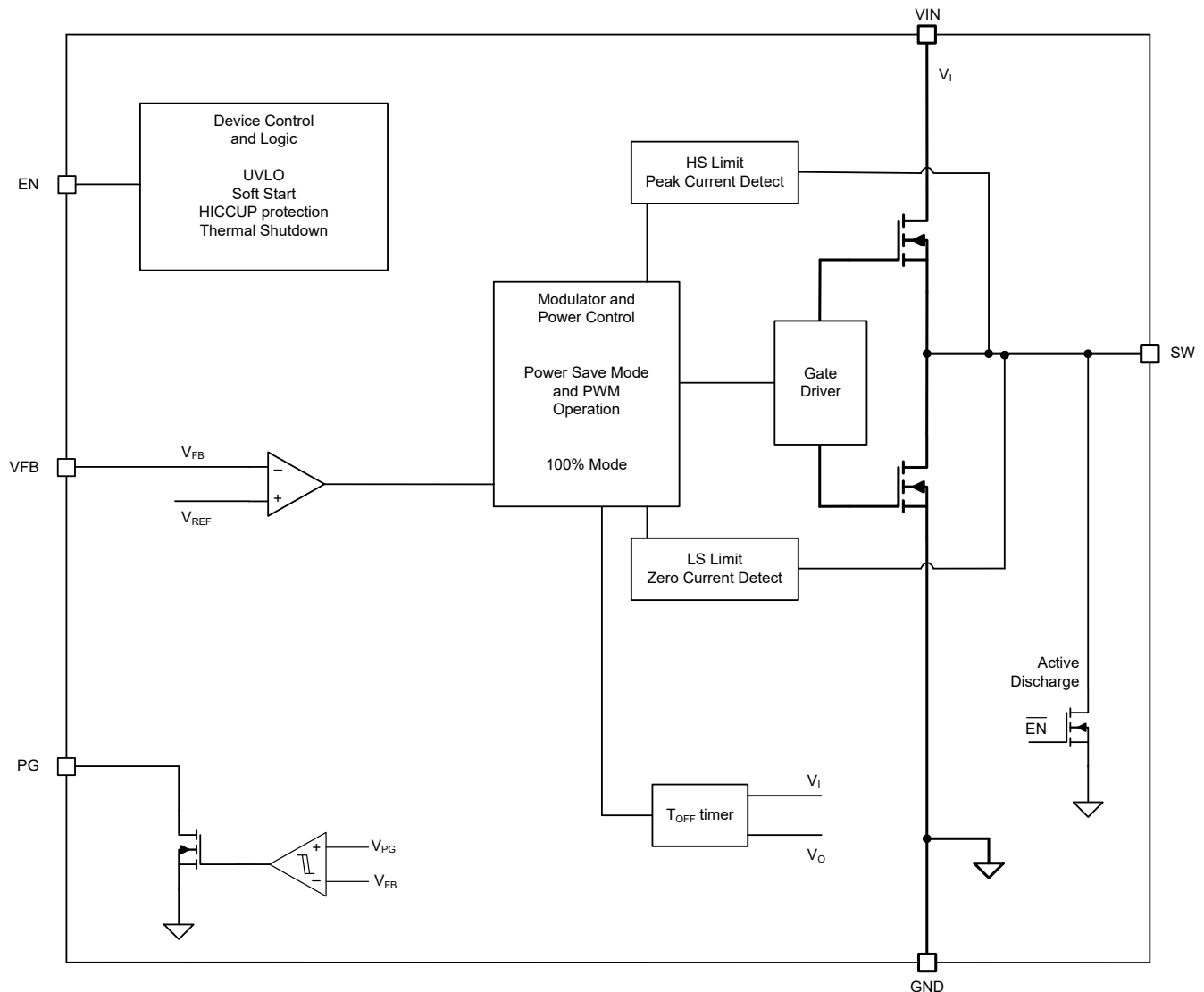
6-2. Shutdown Current vs Junction Temperature

7 Detailed Description

7.1 Overview

The TPS62A01x-Q1 is a high-efficiency synchronous step-down converter. The device operates with an adaptive off time with a peak current control scheme. The device operates typically at 2.4-MHz frequency pulse width modulation (PWM) at moderate to heavy load currents. Based on the V_{IN}/V_{OUT} ratio, a simple circuit sets the required off time for the low-side MOSFET, making the switching frequency relatively constant regardless of the variation of the input voltage, output voltage, and load current.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Power Save Mode

The device automatically enters power save mode to improve efficiency at light load when the inductor current becomes discontinuous. In power save mode, the converter reduces the switching frequency and minimizes current consumption. In power save mode, the output voltage rises slightly above the nominal output voltage. This effect is minimized by increasing the output capacitor or adding a feedforward capacitor.

7.3.2 100% Duty Cycle Low Dropout Operation

The device offers low input-to-output voltage difference by entering 100% duty cycle mode. In this mode, the high-side MOSFET switch is constantly turned on and the low-side MOSFET is switched off. The minimum input voltage to maintain output regulation, depending on the load current and output voltage, is calculated as:

$$V_{IN(MIN)} = V_{OUT} + I_{OUT} \times (R_{DS(ON)} + R_L) \quad (1)$$

where

- $R_{DS(ON)}$ = High-side FET on-resistance
- R_L = Inductor ohmic resistance (DCR)

7.3.3 Soft Start

After enabling the device, internal soft-start circuitry ramps up the output voltage, which reaches the nominal output voltage during start-up time, avoiding excessive inrush current and creating a smooth voltage rise slope. It also prevents excessive voltage drops of primary cells and rechargeable batteries with high internal impedance.

The TPS62A01x-Q1 is able to start into a prebiased output capacitor. The converter starts with the applied bias voltage and ramps the output voltage to the nominal value.

7.3.4 Switch Current Limit and Short-Circuit Protection (HICCUP)

The switch current limit prevents the device from high inductor current and drawing excessive current from the battery or input rail. Due to internal propagation delay, the AC peak current can exceed the static current limit during that time. Excessive current can occur with a shorted or saturated inductor, an overload or shorted output circuit condition. If the inductor current reaches the threshold I_{LIM} , the high-side MOSFET is turned off and the low-side MOSFET is turned on to ramp down the inductor current with an adaptive off time.

When this switch current limit is triggered 32 times, the device stops switching to protect the output. The device then automatically starts a new start-up after a typical delay time of 100 μ s has passed. This action is named HICCUP short-circuit protection. The device repeats this mode until the high load condition disappears. HICCUP protection is also enabled during the start-up.

7.3.5 Undervoltage Lockout

To avoid misoperation of the device at low input voltages, an undervoltage lockout (UVLO) is implemented, which shuts down the device at voltages lower than V_{UVLO} .

7.3.6 Thermal Shutdown

The device goes into thermal shutdown and stops switching when the junction temperature exceeds T_{JSD} . When the device temperature falls below the threshold by 20°C, the device returns to normal operation automatically.

7.4 Device Functional Modes

7.4.1 Enable and Disable

The device is enabled by setting the EN input to a logic High. Accordingly, a logic Low disables the device. If the device is enabled, the internal power stage starts switching and regulates the output voltage to the set point voltage. The EN input must be terminated and should not be left floating.

7.4.2 Power Good

The TPS62A01x-Q1 has a built-in power-good (PG) feature to indicate whether the output voltage has reached the target and the device is ready. The PG signal can be used for start-up sequencing of multiple rails. The PG pin is an open-drain output that requires a pullup resistor to any voltage up to the recommended input voltage level. PG is low when the device is turned off due to EN, UVLO (undervoltage lockout), or thermal shutdown. VIN must remain present for the PG pin to stay low. If not used, the power good can be tie to GND or left open. The PG indicator has a de-glitch to avoid the signal indicating glitches or transient responses from the loop.

表 7-1. Power-Good indicator Functional Table

Logic Signals				PG Status
V_I	EN Pin	Thermal Shutdown	V_O	
$V_I > UVLO$	HIGH	NO	V_O on target	High Impedance
			$V_O < target$	LOW
		YES	LOW	
	YES	x	LOW	
	$UVLO < V_I < 1.8 V$	x	x	LOW
$V_I < 1.8 V$	x	x	x	Undefined

8 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The following section discusses the design of the external components to complete the power supply design for several input and output voltage options by using typical applications as a reference.

8.2 Typical Application

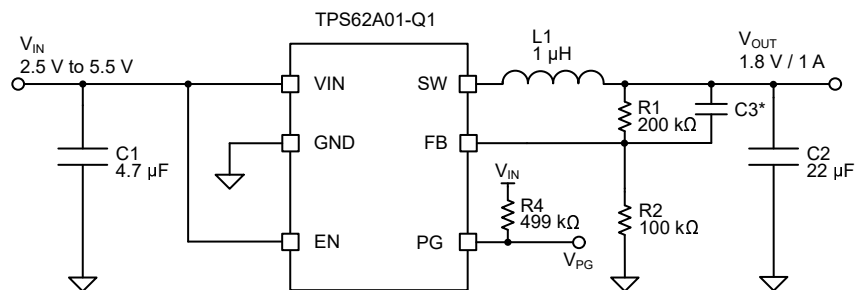


図 8-1. TPS62A01x-Q1 Typical Application Circuit

*C3 is optional

8.2.1 Design Requirements

For this design example, use the parameters listed in 表 8-1 as the input parameters

表 8-1. Design Parameters

Design Parameter	Example Value
Input voltage	2.5 V to 5.5 V
Output voltage	1.8 V
Maximum output current	1.0 A

表 8-2 lists the components used for the example.

表 8-2. List of Components

Reference	Description	Manufacturer ⁽¹⁾
C1	4.7 μF, Ceramic Capacitor, 10 V, X7R, size 0805, GRM21BR71A475KA73L	Murata
C2	22 μF, Ceramic Capacitor, 10 V, X7R, size 0805, GRM21BZ71A226KE15L	Murata
L1	1 μH, Power Inductor, XGL3520-102MEC	Coilcraft
R1, R2	Chip resistor, 1%, size 0603	Std.
C3	Optional, 27 pF or 33 pF if needed ⁽²⁾	Std.

(1) See the [Third-Party Products Disclaimer](#).

(2) TI recommends 33 pF for ≤1.8-V output voltage and 27 pF for 3.3-V output voltage.

8.2.2 Detailed Design Procedure

8.2.2.1 Setting the Output Voltage

The output voltage is set by an external resistor divider according to 式 2.

$$R1 = R2 \times \left(\frac{V_{OUT}}{V_{FB}} - 1 \right) = R2 \times \left(\frac{V_{OUT}}{0.6V} - 1 \right) \quad (2)$$

R2 must not be higher than 100 kΩ to provide acceptable noise sensitivity.

8.2.2.2 Output Filter Design

The inductor and output capacitor together provide a low-pass filter. To simplify this process, 表 8-3 outlines possible inductor and capacitor value combinations. Please note that stability may vary based on board layout and parasitic elements and it is essential to evaluate and confirm the appropriate values for each specific application. Checked cells represent combinations that are proven for stability by simulation and lab test. Further combinations should be checked for each individual application.

In case a lower output ripple is desired, higher output capacitance may help reduce the ripple.

表 8-3. Matrix of Output Capacitor and Inductor Combinations for TPS62A01x-Q1

V _{OUT} [V]	L [μH] ⁽¹⁾	C _{OUT} [μF] ⁽²⁾		
		10	22	2 × 22
0.6 ≤ V _{OUT} < 1.2	1		+	++ ⁽³⁾
1.2 ≤ V _{OUT} < 1.8	1	+ ⁽⁴⁾	++ ⁽³⁾	+
1.8 ≤ V _{OUT}	1	+ ⁽⁴⁾	++ ⁽³⁾	+

- (1) Inductor tolerance and current de-rating is anticipated. The effective inductance can vary by +20% and –30%.
- (2) Capacitance tolerance and bias voltage de-rating is anticipated. The effective capacitance can vary by +20% and –50%.
- (3) This LC combination is the standard value and recommended for most applications.
- (4) The minimum C_{OUT} of 10 μF does not support an additional feedforward capacitor.

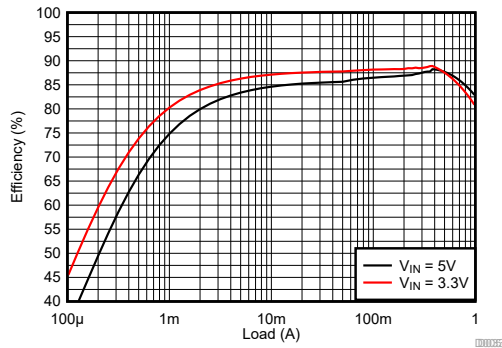
8.2.2.3 Input and Output Capacitor Selection

The architecture of the TPS62A01x-Q1 allows use of tiny ceramic-type output capacitors with low equivalent series resistance (ESR). These capacitors provide low output voltage ripple and are thus recommended. To keep the resistance up to high frequencies and to achieve narrow capacitance variation with temperature, TI recommends to use X7R dielectric.

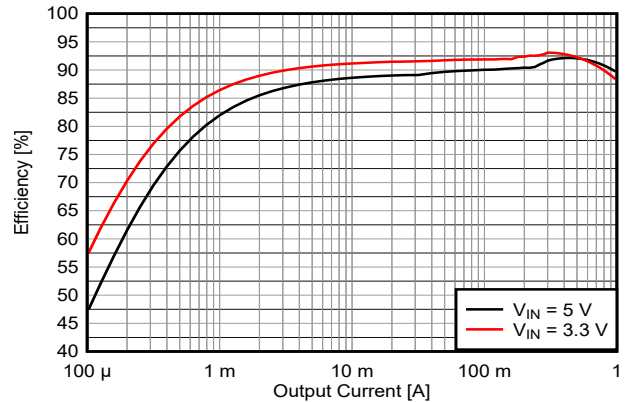
The input capacitor is the low impedance energy source for the converter that helps provide stable operation. TI recommends a low-ESR multilayer ceramic capacitor for best filtering. For most applications, a 4.7-μF input capacitor is sufficient; a larger value reduces input voltage ripple.

A feedforward capacitor reduces the output ripple in PSM and improves the load transient response. A 33-pF capacitor is good for the 1.8-V output typical application. For the 3.3-V output typical application a 27-pF capacitor is recommended.

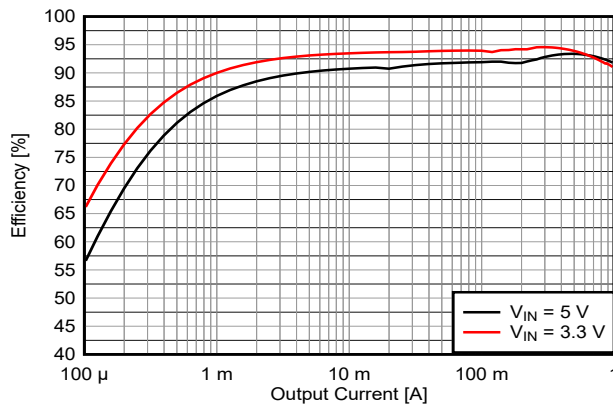
8.2.3 Application Curves



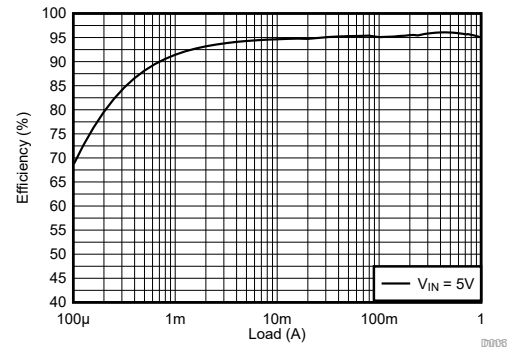
8-2. 0.6-V Output Efficiency (TPS62A01-Q1)



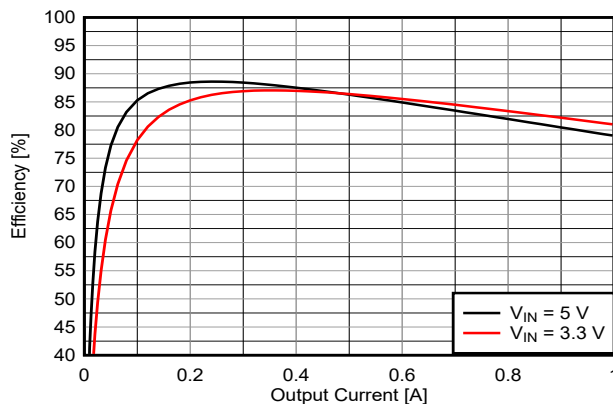
8-3. 1.2-V Output Efficiency (TPS62A01-Q1)



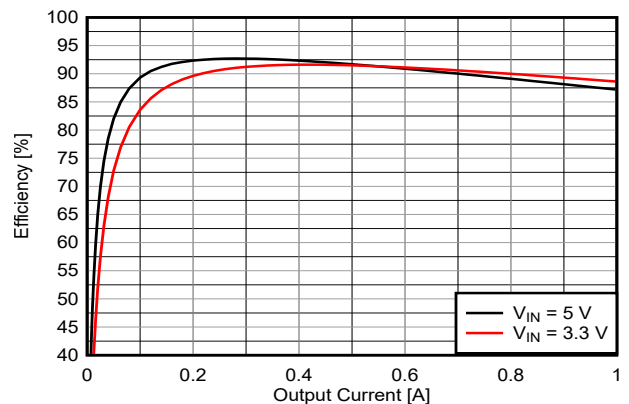
8-4. 1.8-V Output Efficiency (TPS62A01-Q1)



8-5. 3.3-V Output Efficiency (TPS62A01-Q1)



8-6. 0.6-V Output Efficiency (TPS62A01A-Q1)



8-7. 1.2-V Output Efficiency (TPS62A01A-Q1)

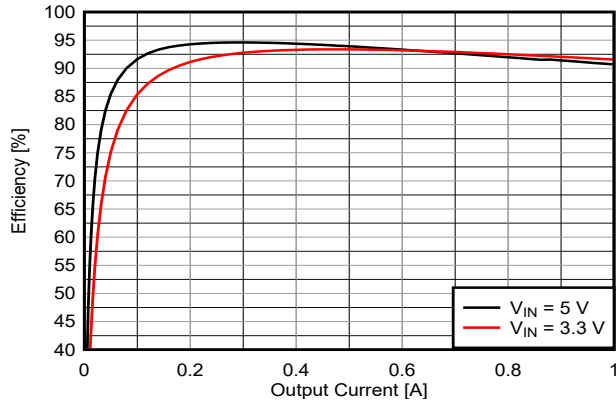


図 8-8. 1.8-V Output Efficiency (TPS62A01A-Q1)

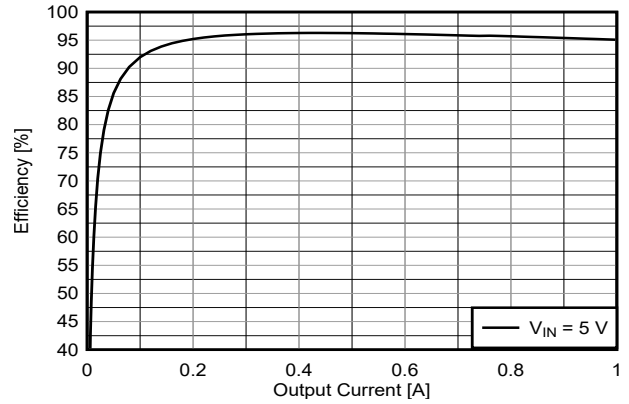


図 8-9. 3.3-V Output Efficiency (TPS62A01A-Q1)

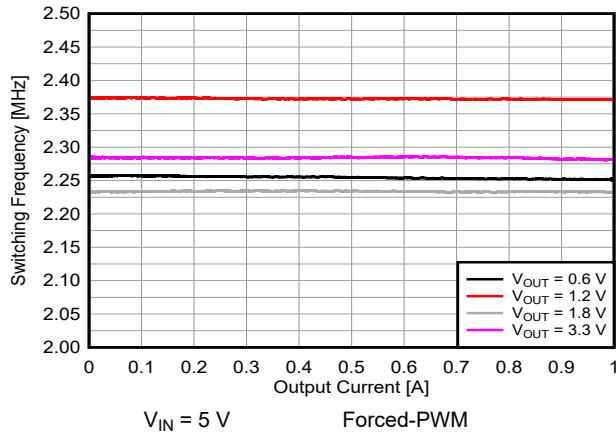


図 8-10. Switching Frequency vs. Output Current

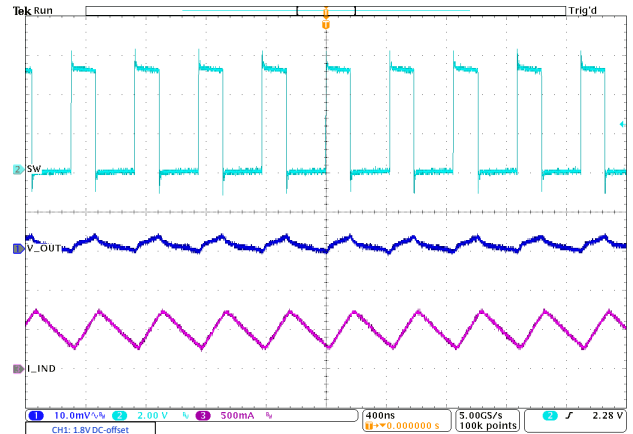


図 8-11. PWM Operation

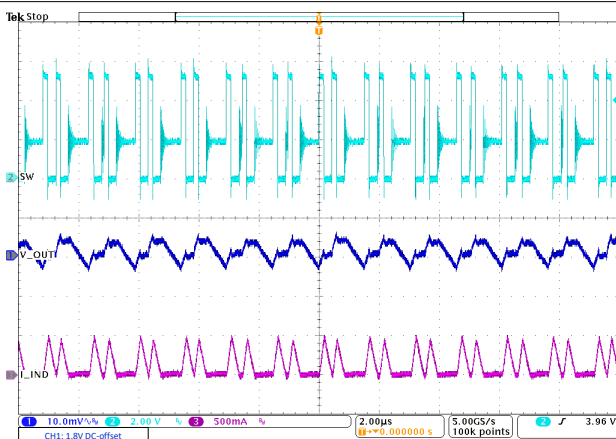


図 8-12. Power Save Mode Operation

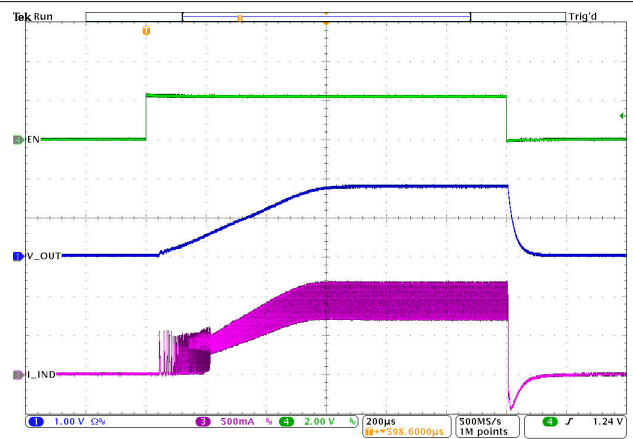
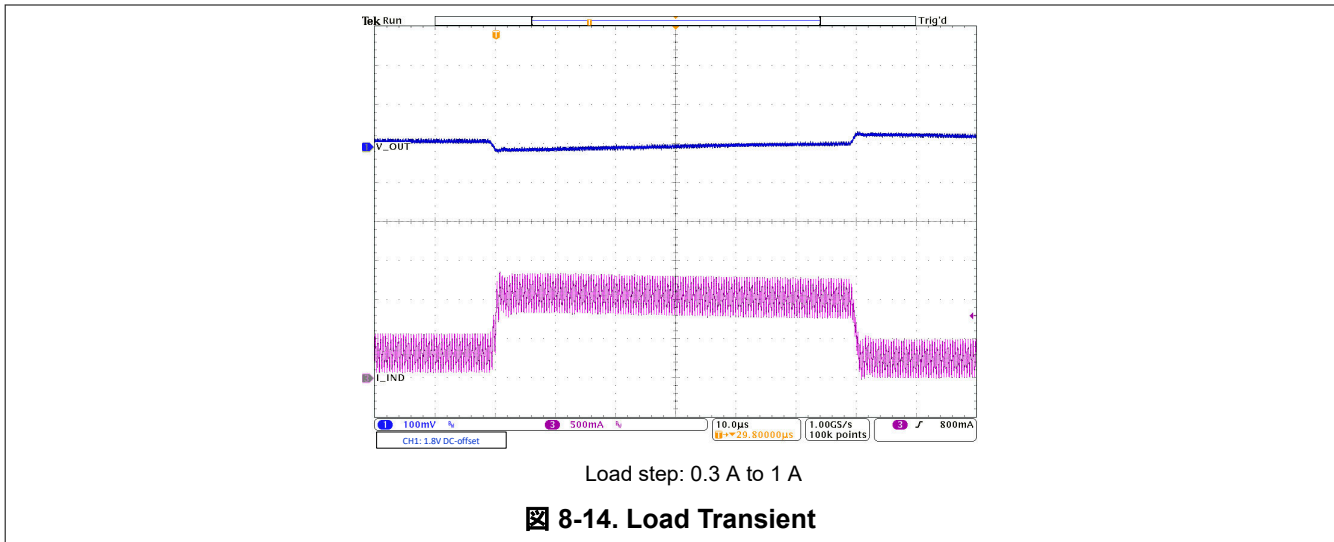


図 8-13. Start-Up with Load



8.3 Power Supply Recommendations

The device is designed to operate from an input voltage supply range from 2.5 V to 5.5 V. Make sure that the input power supply has a sufficient current rating for the application.

8.4 Layout

8.4.1 Layout Guidelines

The printed-circuit-board (PCB) layout is an important step to maintain the high performance of the TPS62A01x-Q1 device.

- The input, output capacitors and the inductor must be placed as close as possible to the IC. This action keeps the power traces short. Routing these power traces direct and wide results in low trace resistance and low parasitic inductance.
- The low side of the input and output capacitors must be connected properly to the GND pin to avoid a ground potential shift.
- The sense traces connected to FB is a signal trace. Special care must be taken to avoid noise being induced. Keep these traces away from SW nodes.
- A common ground must be used. GND layers can be used for shielding.

See [図 8-15](#) for the recommended PCB layout.

8.4.2 Layout Example

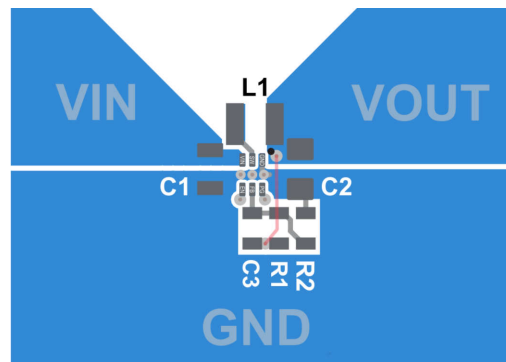


図 8-15. TPS62A01x-Q1 PCB Layout Recommendation

9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Device Support

9.1.1 サード・パーティ製品に関する免責事項

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9.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、www.tij.co.jp のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

9.3 サポート・リソース

[テキサス・インスツルメンツ E2E™ サポート・フォーラム](#)は、エンジニアが検証済みの回答と設計に関するヒントをエキスパートから迅速かつ直接得ることができる場所です。既存の回答を検索したり、独自の質問をしたりすることで、設計に必要な支援を迅速に得ることができます。

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9.4 Trademarks

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9.5 静電気放電に関する注意事項



この IC は、ESD によって破損する可能性があります。テキサス・インスツルメンツは、IC を取り扱う際には常に適切な注意を払うことを推奨します。正しい取り扱いおよび設置手順に従わない場合、デバイスを破損するおそれがあります。

ESD による破損は、わずかな性能低下からデバイスの完全な故障まで多岐にわたります。精密な IC の場合、パラメータがわずかに変化するだけで公表されている仕様から外れる可能性があるため、破損が発生しやすくなっています。

9.6 用語集

[テキサス・インスツルメンツ用語集](#) この用語集には、用語や略語の一覧および定義が記載されています。

10 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision * (February 2023) to Revision A (November 2023) Page

- | | |
|--|---|
| • データシート全体の最初の公開リリース..... | 1 |
| • ドキュメントのステータスを「事前情報」から「量産データ」に変更..... | 1 |

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS62A01AQDRLRQ1	ACTIVE	SOT-5X3	DRL	6	4000	RoHS & Green	Call TI SN	Level-1-260C-UNLIM	-40 to 125	1OH	Samples
TPS62A01QDRLRQ1	ACTIVE	SOT-5X3	DRL	6	4000	RoHS & Green	Call TI SN	Level-1-260C-UNLIM	-40 to 125	1OG	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF TPS62A01-Q1, TPS62A01A-Q1 :

- Catalog : [TPS62A01](#), [TPS62A01A](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS62A01AQDRLRQ1	SOT-5X3	DRL	6	4000	180.0	8.4	2.0	1.8	0.75	4.0	8.0	Q3
TPS62A01QDRLRQ1	SOT-5X3	DRL	6	4000	180.0	8.4	2.0	1.8	0.75	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS62A01AQDRLRQ1	SOT-5X3	DRL	6	4000	210.0	185.0	35.0
TPS62A01QDRLRQ1	SOT-5X3	DRL	6	4000	210.0	185.0	35.0

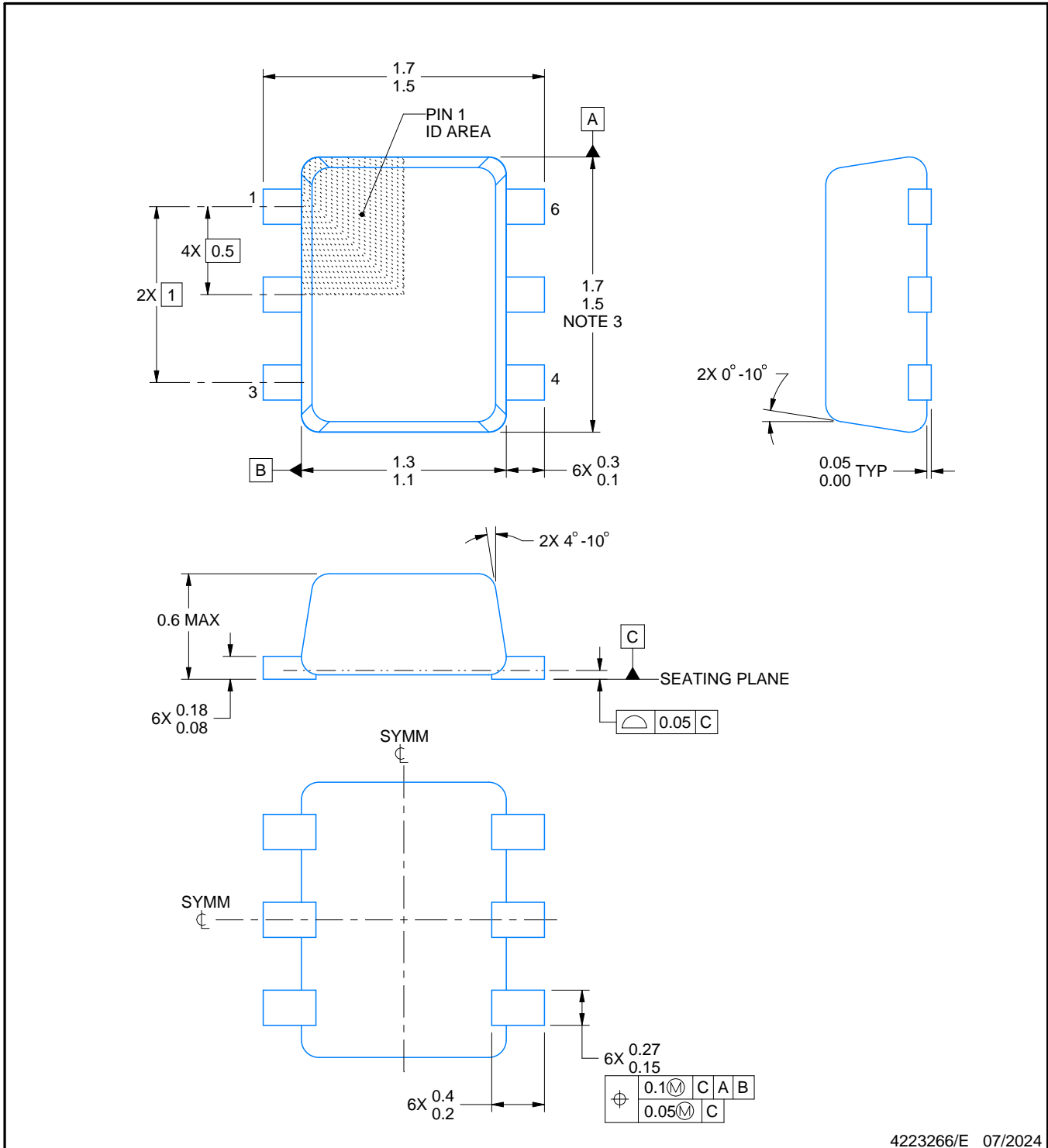
DRL0006A



PACKAGE OUTLINE

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



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NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-293 Variation UAAD

EXAMPLE BOARD LAYOUT

DRL0006A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE
SCALE:30X



SOLDERMASK DETAILS

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NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
7. Land pattern design aligns to IPC-610, Bottom Termination Component (BTC) solder joint inspection criteria.

EXAMPLE STENCIL DESIGN

DRL0006A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:30X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

重要なお知らせと免責事項

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